

Dependence of the electronic structure of self-assembled (\ln , Ga) As/Ga As quantum dots on height and composition

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7]hUh]cb. >ci fbU`cZ5dd`]YX`D\ng]Vg`98ž\$(' +\$, f&\$\$) {/Xc]. %\$"%\$*' #%%, \$) ' (J]Yk cbcYk \$) ' (

Dependence of the electronic structure of self-assembled (In,Ga)As/GaAs quantum dots on height and composition

 $\mathbf{G} \mathbf{u} = \mathbf{A} \cdot \mathbf{N} \mathbf{a} = \mathbf{A} \cdot \mathbf{G} \mathbf{a} = \mathbf{B} \quad , \quad \mathbf{A} \times \mathbf{Z} \mathbf{u} = \mathbf{a} \quad \\ , \quad \mathbf{B} \otimes \mathbf{A} \otimes \mathbf{A}$

 \mathcal{H}_{i} , $\frac{\beta}{i} \nabla_{i}$, $\beta = \sum_{i}$

 $\sum_{i=1}^{n-1} \sum_{i=1}^{n-1} \sum_{i=1}^{n-1}$

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 $\sum_{i=1}^{n} \left(\frac{1}{2} \right) = \sum_{i=1}^{n} \left(\frac{1}{2} \right) = \frac{1}{2} \left(\frac{1}{2} \right$



 $\begin{array}{c} t_{1} = t_{1} =$



IV. SUMMARY

 $\begin{array}{c} (...) = \left[\begin{array}{c} 1 \\ -1 \end{array} \right] = \left[\begin{array}{c} 1 \end{array}] = \left[\begin{array}{c} 1 \\ -1 \end{array}] = \left[\begin{array}{c} 1 \end{array} \right] = \left[\begin{array}{c} 1 \\ -1 \end{array}] = \left[\begin{array}{c} 1 \end{array}] = \left[\begin{array}{c} 1$

2. Number of k points